

MOSFETs Silicon P-Channel MOS (U-MOSVI)

# SSM3J132TU

### 1. Applications

· Power Management Switches

### 2. Features

- (1) 1.2-V drive
- (2) Low drain-source on-resistance

:  $R_{DS(ON)} = 94 \text{ m}\Omega \text{ (max) (V}_{GS} = -1.2 \text{ V)}$ 

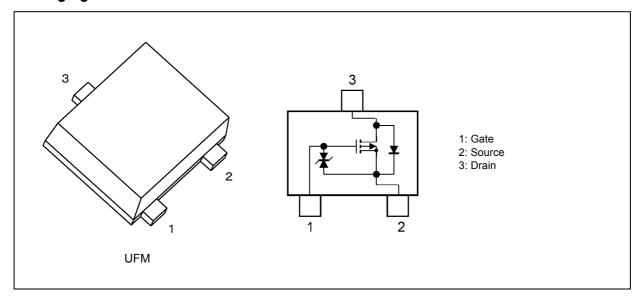
 $R_{DS(ON)} = 39 \text{ m}\Omega \text{ (max) (V}_{GS} = -1.5 \text{ V)}$ 

 $R_{DS(ON)} = 29 \text{ m}\Omega \text{ (max) (V}_{GS} = -1.8 \text{ V)}$ 

 $R_{DS(ON)} = 21 \text{ m}\Omega \text{ (max) (V}_{GS} = -2.5 \text{ V)}$ 

 $R_{DS(ON)}$  = 17 m $\Omega$  (max) (V<sub>GS</sub> = -4.5 V)

### 3. Packaging and Internal Circuit



Start of commercial production



### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Cha	racteristics		Symbol	Rating	Unit
Drain-source voltage			$V_{DSS}$	-12	V
Gate-source voltage			$V_{GSS}$	±6	V
Drain current (DC)		(Note 1)	$I_D$	-5.4	Α
Drain current (pulsed)	,	(Note 1), (Note 2)	$I_{DP}$	-10.8	
Power dissipation		(Note 3)	$P_D$	500	mW
Power dissipation	t ≤ 1 s	(Note 3)		1000	
Channel temperature	·		$T_ch$	150	ů
Storage temperature			T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150 °C.
- Note 2: Pulse width (PW)  $\leq$  10 ms, duty = 1 %
- Note 3: Device mounted on an 25.4 mm × 25.4 mm × 1.6 mm FR4 glass epoxy board (Cu pad: 645 mm<sup>2</sup>)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, R<sub>th(ch-a)</sub>, and the drain power dissipation, P<sub>D</sub>, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



#### 5. Electrical Characteristics

### 5.1. Static Characteristics (T<sub>a</sub> = 25 °Cunless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 6 \text{ V}$	_	_	±1	μА
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V	_	_	-1	
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 0 V	-12	_	_	V
Drain-source breakdown voltage	(Note 1)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 5 V	-7	_	_	
Gate threshold voltage	(Note 2)	V <sub>th</sub>	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$	-0.3	_	-1.0	
Drain-source on-resistance	(Note 3)	R <sub>DS(ON)</sub>	I <sub>D</sub> = -5.0 A, V <sub>GS</sub> = -4.5 V	_	14	17	mΩ
			I <sub>D</sub> = -5.0 A, V <sub>GS</sub> = -2.5 V	_	17	21	
			I <sub>D</sub> = -3.5 A, V <sub>GS</sub> = -1.8 V	_	20	29	
			I <sub>D</sub> = -1.5 A, V <sub>GS</sub> = -1.5 V	_	23	39	
			I <sub>D</sub> = -0.4 A, V <sub>GS</sub> = -1.2 V	_	31	94	
Forward transfer admittance	(Note 3)	Y <sub>fs</sub>	V <sub>DS</sub> = -3 V, I <sub>D</sub> = -2.0 A	11.0	22.0	_	S

- Note 1: If a forward bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.
- Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (-1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

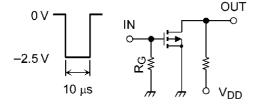
  Take this into consideration when using the device.

Note 3: Pulse measurement.

### 5.2. Dynamic Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$	_	2700		pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	_	525		
Output capacitance	Coss		_	525		
Switching time (turn-on time)	t <sub>on</sub>	$V_{DD} = -10 \text{ V}, I_{D} = -1.0 \text{ A},$ $V_{GS} = 0 \text{ to } -2.5 \text{ V}, R_{G} = 4.7 \Omega$		38		ns
Switching time (turn-off time)	t <sub>off</sub>	Duty $\leq$ 1%, Input: $t_r$ , $t_f$ < 5 ns Common source	_	210		

### 5.3. Switching Time Test Circuit



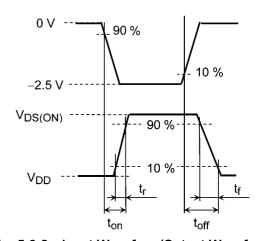


Fig. 5.3.1 Test Circuit of Switching Time

Fig. 5.3.2 Input Waveform/Output Waveform

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## 5.4. Gate Charge Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD}$ = -6 V, $I_{DS}$ = -5.4 A,	_	33.0	_	nC
Gate-source charge 1	Q <sub>gs1</sub>	$V_{GS} = -4.5 \text{ V}$	_	4.3	_	
Gate-drain charge	Q <sub>gd</sub>		_	8.0	_	

## 5.5. Source-Drain Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage (N	ote 1)	$V_{DSF}$	$I_D = 5.4 \text{ A}, V_{GS} = 0 \text{ V}$		0.68	1.0	V

Note 1: Pulse measurement.

### 6. Marking

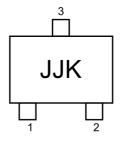


Fig. 6.1 Marking



#### 7. Characteristics Curves (Note)

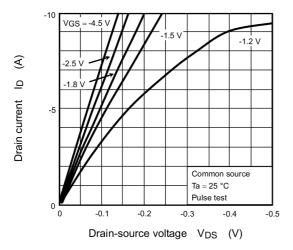


Fig. 7.1 I<sub>D</sub> - V<sub>DS</sub>

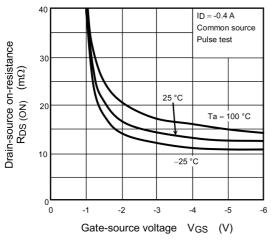


Fig. 7.3 R<sub>DS(ON)</sub> - V<sub>GS</sub>

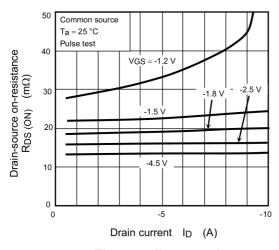


Fig. 7.5 R<sub>DS(ON)</sub> - I<sub>D</sub>

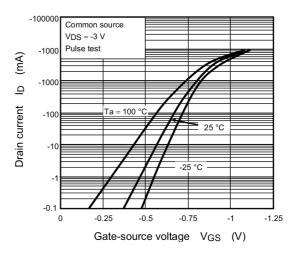


Fig. 7.2 I<sub>D</sub> - V<sub>GS</sub>

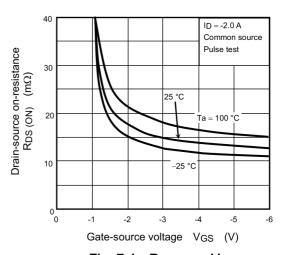


Fig. 7.4 R<sub>DS(ON)</sub> - V<sub>GS</sub>

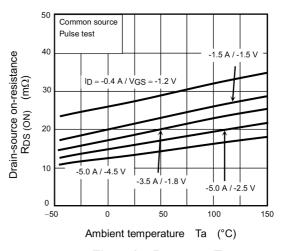


Fig. 7.6 R<sub>DS(ON)</sub> - T<sub>a</sub>



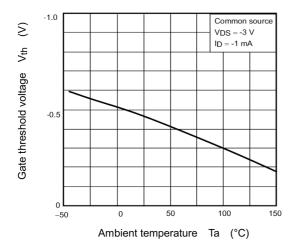


Fig. 7.7  $V_{th}$  -  $T_a$ 

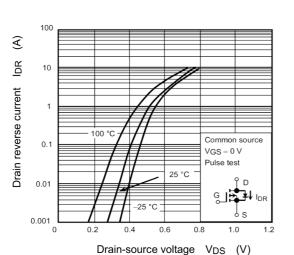
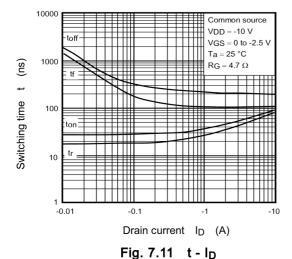


Fig. 7.9 IDR - VDS



 $|Y_{fs}|$ Forward transfer admittance

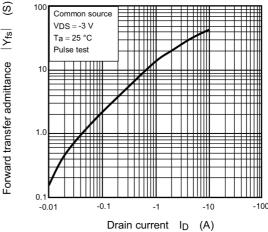


Fig. 7.8 |Y<sub>fs</sub>| - I<sub>D</sub>

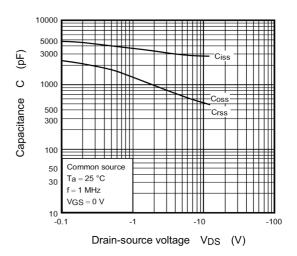


Fig. 7.10 C - V<sub>DS</sub>

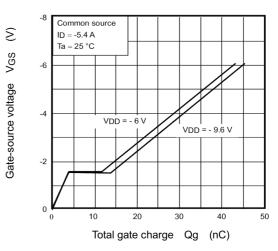


Fig. 7.12 Dynamic Input Characteristics



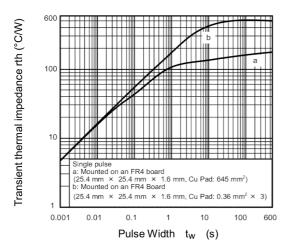
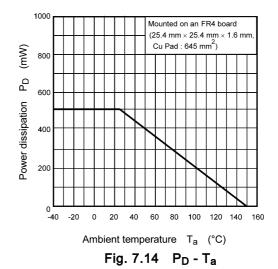


Fig. 7.13 rth - tw



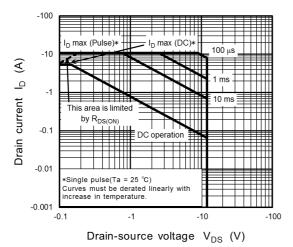


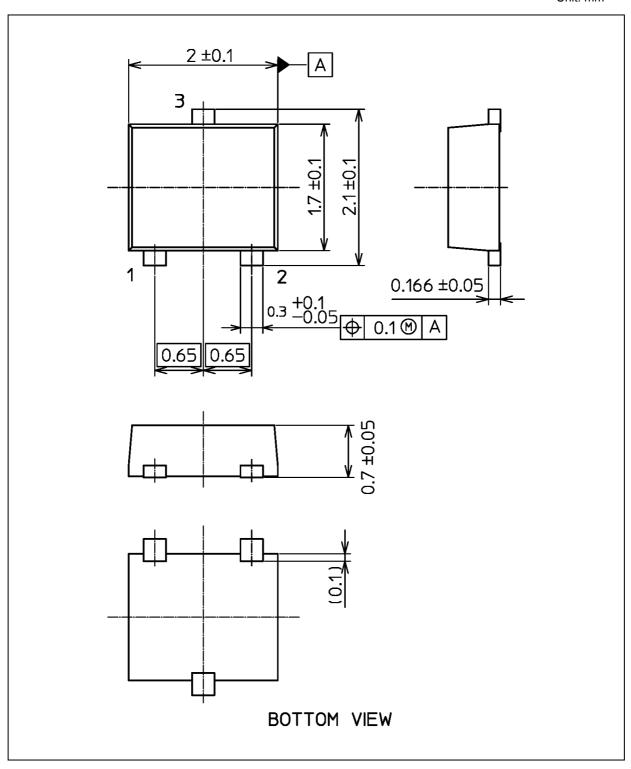
Fig. 7.15 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



Weight: 6.6 mg (typ.)

	Package Name(s)
TOSHIBA: 2-2U1S	
Nickname: UFM	



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